TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SZU04AFE

#### Inverter

#### **Features**

• High output drive: ±16 mA (typ.)

$$@V_{CC} = 3 V$$

• Low quiescent power: ICC < 2 μA (max)

$$@V_{CC} = 5.5 \text{ V}, \text{ Ta} = 25^{\circ}\text{C}$$

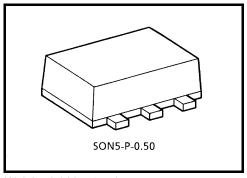
• Operation voltage range:  $V_{CC (opr)} = 1.8 \sim 5.5 \text{ V}$ 

• Supply voltage data retention:  $V_{CC} = 1.5 \sim 5.5 \text{ V}$ 

• Latch-up performance: ±500 mA

• ESD performance: Human body model >  $\pm 2000 \text{ V}$  Machine model >  $\pm 200 \text{ V}$ 

· Power down protection is provided on all inputs.



Weight: 0.003 g (typ.)

#### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5~6	V
DC input voltage	V <sub>IN</sub>	-0.5~6	V
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5	V
Input diode current	l <sub>IK</sub>	±20	mA
Output diode current	I <sub>OK</sub>	±20	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	I <sub>CC</sub>	±50	mA
Power dissipation	P <sub>D</sub>	150	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C
Lead temperature (10 s)	TL	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



# **Operating Ranges**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	1.8~5.5	V	
Supply Voltage	VCC	1.5~5.5 (Note 1)	·	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	-40~85	°C	

Note 1: Data retention only.

### **Electrical Characteristics**

#### **DC Characteristics**

OL Test						Га = 25°C		Ta = -40~85°C			
Characteristics	Symbol	ymbol Circuit		Test Condition		Min	Тур.	Max	Min	Max	Unit
High-level input voltage				1.8	0.85 × V <sub>CC</sub>	_	_	0.85 × V <sub>CC</sub>		· v	
				2.3- 5.5	0.8 × V <sub>CC</sub>	_	_	0.8 × V <sub>CC</sub>	_		
Low-level input		., .,		1.8	_	_	0.15 × V <sub>CC</sub>	_	0.15 × V <sub>CC</sub>	.,	
voltage		$V_{IN} = V_{IH}$ or $V_{IL}$		2.3- 5.5	_	_	0.2 × V <sub>CC</sub>	_	0.2 × V <sub>CC</sub>	V	
					1.8	1.6	1.8	_	1.6	_	
			V <sub>IN</sub> =	lou = 100 uA	2.3	2.1	2.3	_	2.1	_	
			VIL	$I_{OH} = -100 \mu A$	3.0	2.7	3.0	_	2.7	_	
High-level output voltage VOH				4.5	4.0	4.4	_	4.0	_	V	
	VOH		V <sub>IN</sub> = GND	I <sub>OH</sub> = -4 mA	2.3	1.9	2.14	_	1.9	_	V
				$I_{OH} = -8 \text{ mA}$	3.0	2.4	2.75	_	2.4		
				I <sub>OH</sub> = -12 mA	3.0	2.3	2.61	_	2.3	_	
					I <sub>OH</sub> = -16 mA	4.5	3.8	4.13	_	3.8	_
			V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 100 μA	1.8	_	0	0.2	_	0.2	-
					2.3	_	0	0.2	_	0.2	
					3.0	_	0	0.3	_	0.3	
Low-level output voltage				4.5	_	0	0.5	_	0.5	V	
	VOL	L   -		I <sub>OL</sub> = 4 mA	2.3	_	0.1	0.3	_	0.3	v
		V <sub>IN</sub> =	I <sub>OL</sub> = 8 mA	3.0	_	0.17	0.4	_	0.4		
			V <sub>CC</sub>	I <sub>OL</sub> = 12 mA	3.0	_	0.25	0.55	_	0.55	
				I <sub>OL</sub> = 16 mA	4.5	_	0.26	0.55	_	0.55	
Input leakage current	I <sub>IN</sub>		V <sub>IN</sub> = 5.5 V or GND		0- 5.5	_	1	±1	_	±10	μА
Quiescent supply current	Icc	_	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	2	_	20	μА

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#### AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics Symbol		Test	Test Test Condition		Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Characteristics Symbol Circui	Circuit	t rest Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
Propagation delay tPLH time tPHL		$C_L$ = 15 pF, $R_L$ = 1 M $\Omega$	1.8	1.0	_	8.5	1.0	9.0	- ns	
			$2.5 \pm 0.2$	0.8	_	6.2	8.0	6.5		
	_		$3.3 \pm 0.3$	0.5	_	4.5	0.5	4.8		
			5.0 ± 0.5	0.5	_	3.9	0.5	4.1		
		$\begin{aligned} C_L &= 50 \text{ pF}, \\ R_L &= 500 \ \Omega \end{aligned}$	$3.3\pm0.3$	1.0	_	6.0	1.0	6.5		
			5.0 ± 0.5	0.8	_	5.0	0.8	5.5		
Input capacitance	C <sub>IN</sub>	_	_	0-5.5		5		_		pF
Power dissipation capacitance	C <sub>PD</sub> —		(Nloto)	3.3		9		_		"F
		(Note)	5.5		25		_		pF	

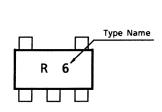
Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

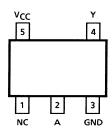
Average operating current can be obtained by the equation.

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## Marking

# Pin Assignment (top view)

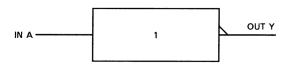




#### **Truth Table**

Α	Y
L	Н
Н	L

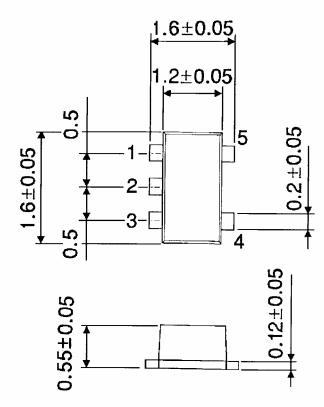
#### **Logic Diagram**





# **Package Dimensions**

SON5-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

#### **RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

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